



MMDT5551

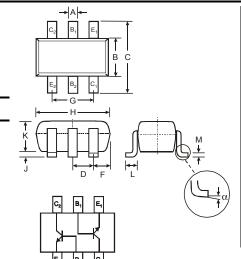
DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMDT5401)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: K4N, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



SOT-363										
Dim	Min	Max								
Α	0.10	0.30								
В	1.15	1.35								
С	2.00	2.20								
D	0.65 N	ominal								
F	0.30	0.40								
Н	1.80	2.20								
J	_	0.10								
K	0.90	1.00								
L	0.25	0.40								
М	0.10	0.25								
α	0°	8°								
All Din	nensions	in mm								

Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Collector-Base Voltage		V_{CBO}	180	V
Collector-Emitter Voltage		V_{CEO}	160	V
Emitter-Base Voltage		V_{EBO}	6.0	V
Collector Current - Continuous	(Note 1)	Ic	200	mA
Power Dissipation	(Note 1, 2)	P _d	200	mW
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{ heta JA}$	625	°C/W
Operating and Storage Temperature Range		T _j , T _{STG}	-55 to +150	°C

Notes:

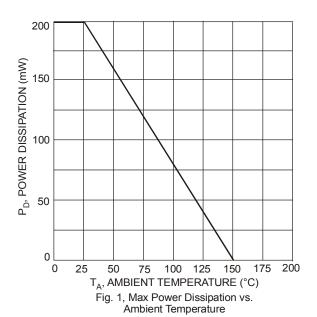
- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. Maximum combined dissipation.
- 3. No purposefully added lead.
- 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

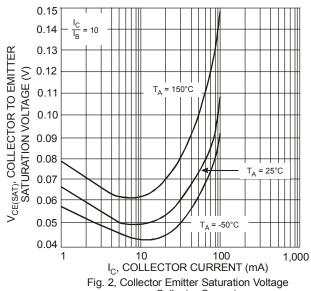


Electrical Characteristics @T_A = 25°C unless otherwise specified

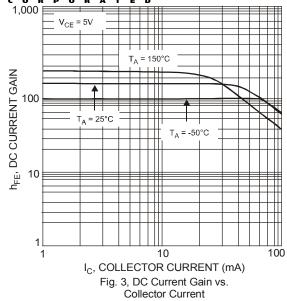
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)	·				
Collector-Base Breakdown Voltage	V _{(BR)CBO}	180	_	V	$I_C = 100 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	160	_	V	$I_C = 1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6.0	_	V	$I_E = 10 \mu A, I_C = 0$
Collector Cutoff Current	Ісво	_	50	nA μA	V _{CB} = 120V, I _E = 0 V _{CB} = 120V, I _E = 0, T _A = 100°C
Emitter Cutoff Current	I _{EBO}	_	50	nA	$V_{EB} = 4.0V, I_{C} = 0$
ON CHARACTERISTICS (Note 6)	·				
DC Current Gain	h _{FE}	80 80 30	250 —	_	I_C = 1.0mA, V_{CE} = 5.0V I_C = 10mA, V_{CE} = 5.0V I_C = 50mA, V_{CE} = 5.0V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.15 0.20	V	I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA
Base-Emitter Saturation Voltage		_	1.0	V	I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA
SMALL SIGNAL CHARACTERISTICS	·				
Output Capacitance	C_{obo}	_	6.0	pF	V _{CB} = 10V, f = 1.0MHz, I _E = 0
Small Signal Current Gain	h _{fe}	50	250		V _{CE} = 10V, I _C = 1.0mA, f = 1.0kHz
Current Gain-Bandwidth Product	f _T	100	300	MHz	V _{CE} = 10V, I _C = 10mA, f = 100MHz
Noise Figure	NF	_	8.0	dB	V_{CE} = 5.0V, I_{C} = 200 μ A, R_{S} = 1.0k Ω , f = 1.0kHz

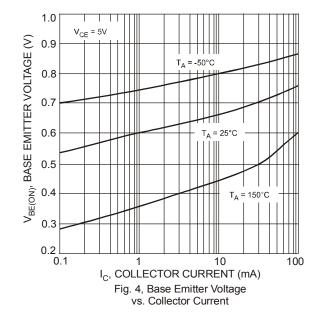
Notes: 6. Short duration pulse test used to minimize self-heating effect.

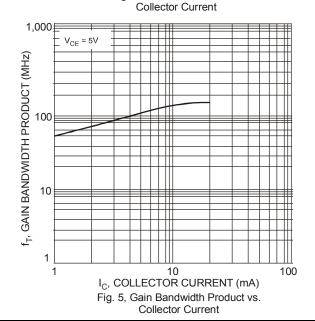










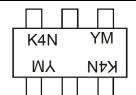


Ordering Information (Note 7)

Device	Packaging	Shipping			
MMDT5551-7-F	SOT-363	3000/Tape & Reel			

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K4N = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

Dute	ouc recy															
	Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
	Code	J	K	L	М	N	Р	R	S	Т	U	V	W	X	Υ	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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